

APPLICATION DATA SHEET

Electronic Version v14

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Title of Invention	METHOD OF FABRICATING LOW TEMPERATURE POLYSILICON THIN FILM TRANSISTOR
Application Type :	regular, utility
Attorney Docket Number :	TOPP0009USA
Correspondence address:	
Customer Number:	027765
	
Inventor Information:	
<u>Inventor 1:</u>	
Applicant Authority Type:	Inventor
Citizenship:	TW
Given Name:	Hui-Chu
Family Name:	Lin
Residence:	
City of Residence:	Hsin-Chu Hsien
Country of Residence:	TW
Address-1 of Mailing Address:	99-5, Shan-Chu-Hu, Chiu-Hu Tsun,
Address-2 of Mailing Address:	
City of Mailing Address:	Hsin-Chu Hsien
State of Mailing Address:	
Postal Code of Mailing Address:	
Country of Mailing Address:	TW
Phone:	
Fax:	
E-mail:	

Attorney Information:

practitioner(s) at Customer Number:

027765



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